NSN 5961-01-007-6812

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-007-6812 **Inclosure Material:** Metal **Overall Length:** 1.025 inches **Overall Diameter:** 0.980 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees fahrenheit ambient air **Terminal Type And Quantity:** 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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